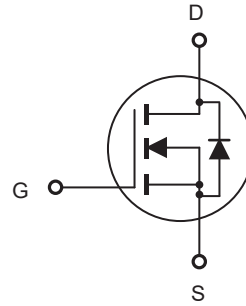
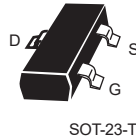


N-Channel Enhancement Mode Field Effect Transistor

FEATURES

- 30V, 4.8A, $R_{DS(ON)} = 34m\Omega$ @ $V_{GS} = 10V$.
 $R_{DS(ON)} = 40m\Omega$ @ $V_{GS} = 4.5V$.
 $R_{DS(ON)} = 45m\Omega$ @ $V_{GS} = 2.5V$.
 $R_{DS(ON)} = 60m\Omega$ @ $V_{GS} = 1.8V$.
- High dense cell design for extremely low $R_{DS(ON)}$.
- Rugged and reliable.
- RoHS compliant.
- SOT-23-T package.



ABSOLUTE MAXIMUM RATINGS $T_A = 25^\circ C$ unless otherwise noted

| Parameter | Symbol | Limit | Units |
|---------------------------------------|----------------|------------|------------|
| Drain-Source Voltage | V_{DS} | 30 | V |
| Gate-Source Voltage | V_{GS} | ± 12 | V |
| Drain Current-Continuous | I_D | 4.8 | A |
| Drain Current-Pulsed ^a | I_{DM} | 20 | A |
| Maximum Power Dissipation | P_D | 1.25 | W |
| Operating and Store Temperature Range | T_J, T_{stg} | -55 to 150 | $^\circ C$ |

Thermal Characteristics

| Parameter | Symbol | Limit | Units |
|--|-----------------|-------|--------------|
| Thermal Resistance, Junction-to-Ambient ^b | $R_{\theta JA}$ | 100 | $^\circ C/W$ |

Electrical Characteristics $T_A = 25^\circ\text{C}$ unless otherwise noted

| Parameter | Symbol | Test Condition | Min | Typ | Max | Units |
|--|--------------|---|-----|-----|------|-----------|
| Off Characteristics | | | | | | |
| Drain-Source Breakdown Voltage | BV_{DSS} | $V_{GS} = 0V, I_D = 250\mu A$ | 30 | | | V |
| Zero Gate Voltage Drain Current | I_{DSS} | $V_{DS} = 30V, V_{GS} = 0V$ | | | 1 | μA |
| Gate Body Leakage Current, Forward | I_{GSSF} | $V_{GS} = 12V, V_{DS} = 0V$ | | | 100 | nA |
| Gate Body Leakage Current, Reverse | I_{GSSR} | $V_{GS} = -12V, V_{DS} = 0V$ | | | -100 | nA |
| On Characteristics ^c | | | | | | |
| Gate Threshold Voltage | $V_{GS(th)}$ | $V_{GS} = V_{DS}, I_D = 250\mu A$ | 0.4 | | 1 | V |
| Static Drain-Source On-Resistance | $R_{DS(on)}$ | $V_{GS} = 10V, I_D = 4.8A$ | | 24 | 34 | $m\Omega$ |
| | | $V_{GS} = 4.5V, I_D = 4A$ | | 26 | 40 | $m\Omega$ |
| | | $V_{GS} = 2.5V, I_D = 2A$ | | 30 | 45 | $m\Omega$ |
| | | $V_{GS} = 1.8V, I_D = 1A$ | | 34 | 60 | $m\Omega$ |
| Dynamic Characteristics ^d | | | | | | |
| Input Capacitance | C_{iss} | $V_{DS} = 15V, V_{GS} = 0V, f = 1.0\text{ MHz}$ | | 520 | | pF |
| Output Capacitance | C_{oss} | | | 85 | | pF |
| Reverse Transfer Capacitance | C_{rss} | | | 60 | | pF |
| Switching Characteristics ^d | | | | | | |
| Turn-On Delay Time | $t_{d(on)}$ | $V_{DD} = 15V, I_D = 4.8A, V_{GS} = 4.5V, R_{GEN} = 10\Omega$ | | 9 | | ns |
| Turn-On Rise Time | t_r | | | 6 | | ns |
| Turn-Off Delay Time | $t_{d(off)}$ | | | 44 | | ns |
| Turn-Off Fall Time | t_f | | | 10 | | ns |
| Total Gate Charge | Q_g | $V_{DS} = 15V, I_D = 4.8A, V_{GS} = 4.5V$ | | 10 | | nC |
| Gate-Source Charge | Q_{gs} | | | 1 | | nC |
| Gate-Drain Charge | Q_{gd} | | | 3 | | nC |
| Drain-Source Diode Characteristics and Maximum Ratings | | | | | | |
| Drain-Source Diode Forward Current ^b | I_S | | | | 1.2 | A |
| Drain-Source Diode Forward Voltage ^c | V_{SD} | $V_{GS} = 0V, I_S = 1A$ | | | 1 | V |
| Notes : a.Repetitive Rating : Pulse width limited by maximum junction temperature. b.Surface Mounted on FR4 Board, $t < 5\text{ sec}$. c.Pulse Test : Pulse Width $\leq 300\mu s$, Duty Cycle $\leq 2\%$. d.Guaranteed by design, not subject to production testing. | | | | | | |

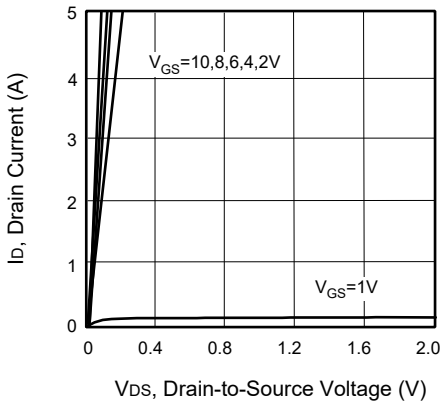


Figure 1. Output Characteristics

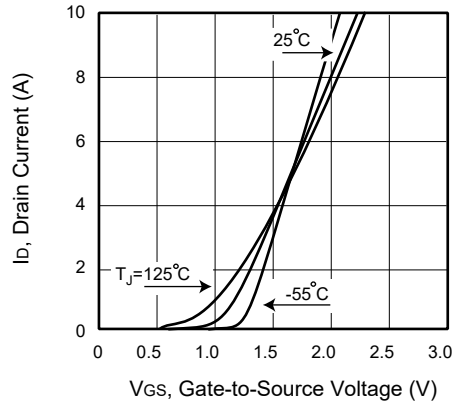


Figure 2. Transfer Characteristics

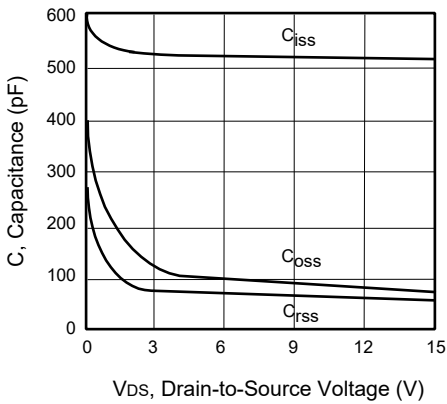


Figure 3. Capacitance

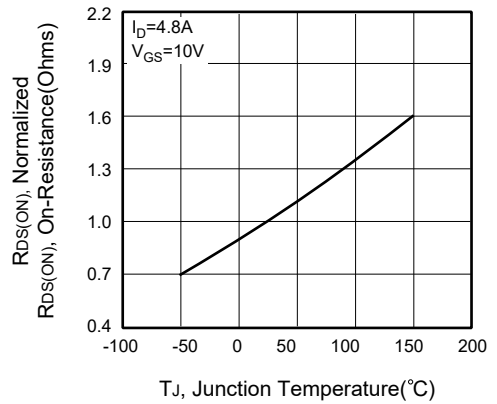


Figure 4. On-Resistance Variation with Temperature

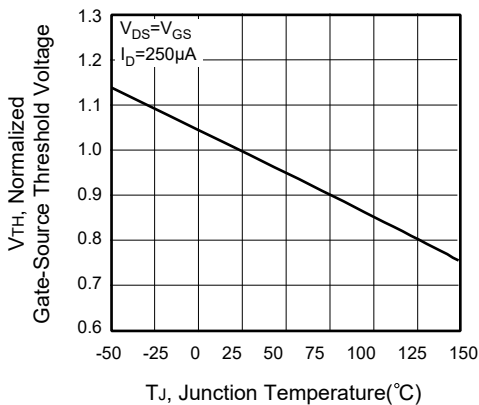


Figure 5. Gate Threshold Variation with Temperature

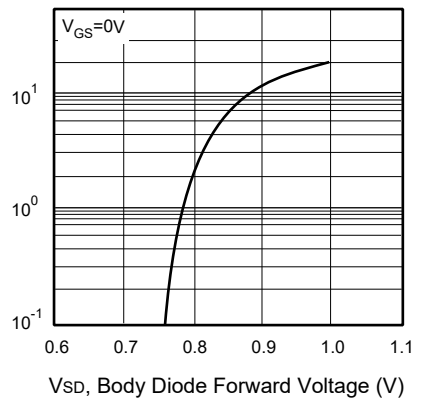


Figure 6. Body Diode Forward Voltage Variation with Source Current

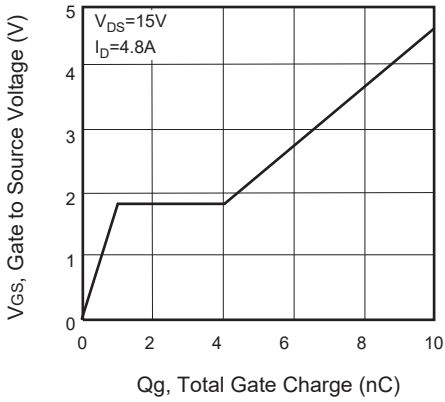


Figure 7. Gate Charge

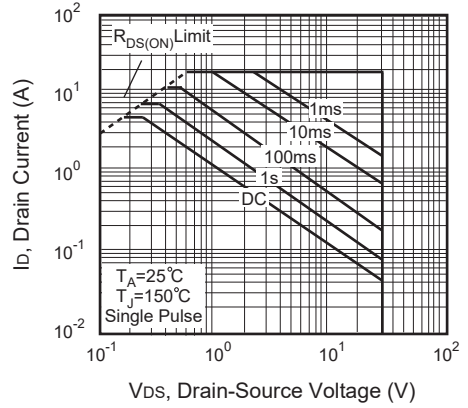


Figure 8. Maximum Safe Operating Area

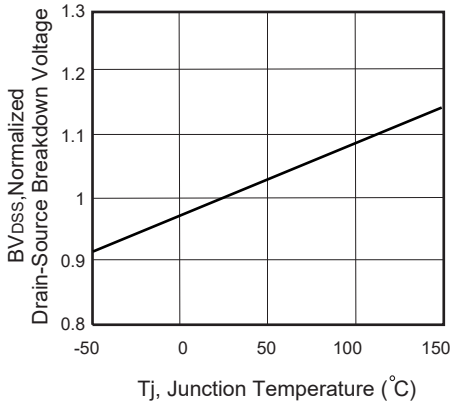


Figure 9. Breakdown Voltage Variation VS Temperature

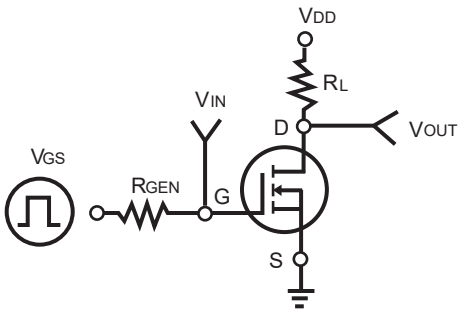


Figure 10. Switching Test Circuit

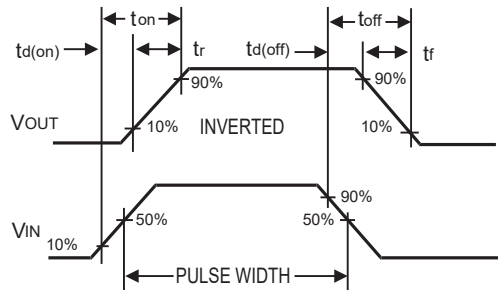


Figure 11. Switching Waveforms

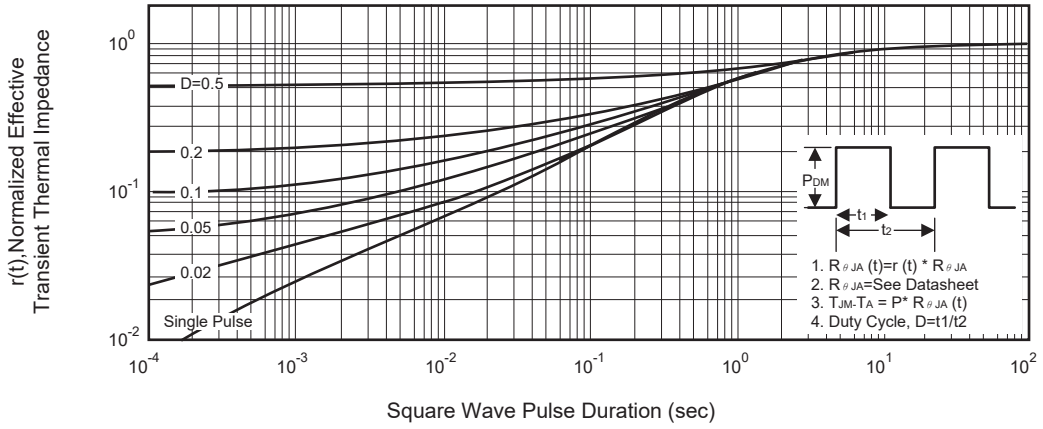


Figure 12. Normalized Thermal Transient Impedance Curve